

BUT12/12A

High Voltage Power Switching Applications



1.Base 2.Collector 3.Emitter

NPN Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		
	: BUT12	850	V
	: BUT12A	1000	V
V _{CEO}	Collector-Emitter Voltage		
	: BUT12	400	V
	: BUT12A	450	V
I _C	Collector Current (DC)	8	Α
I _{CP}	*Collector Current (Pulse)	20	Α
I _B	Base Current	4	Α
P _C	Collector Dissipation (T _C =25°C)	100	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 175	°C

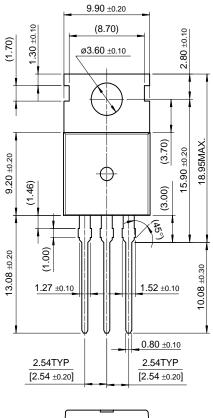
Electrical Characteristics T_{C} =25°C unless otherwise noted

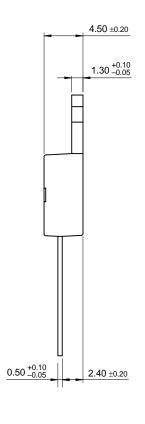
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	* Collector-Emitter Sustaining Voltage	I _C = 100mA, L = 25mH	400			V
I _{CES}	Collector Cut-off Current	$V_{CE} = V_{CES}, V_{BE} = 0$			1	mA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = 9V, I_{C} = 0$			10	mA
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C = 6A, I _B = 1.2A			1.5	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C = 6A, I _B = 1.2A			1.5	V
t _{ON}	Turn On Time	$V_{CC} = 250V, I_{C} = 6A$			1	μs
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = 1.2A$			4	μs
t _F	Fall Time	$R_L = 41.6\Omega$			0.8	μs

^{*} Pulsed Test: PW = $300\mu s$, duty cycle = 1.5%

Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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